

MSW9N90

900V N-Channel MOSFET

Description

This latest technology has been especially designed to minimize on-state resistance, have a high rugged avalanche characteristics. These devices are well suited for high efficiency switch mode power supplies.

Features

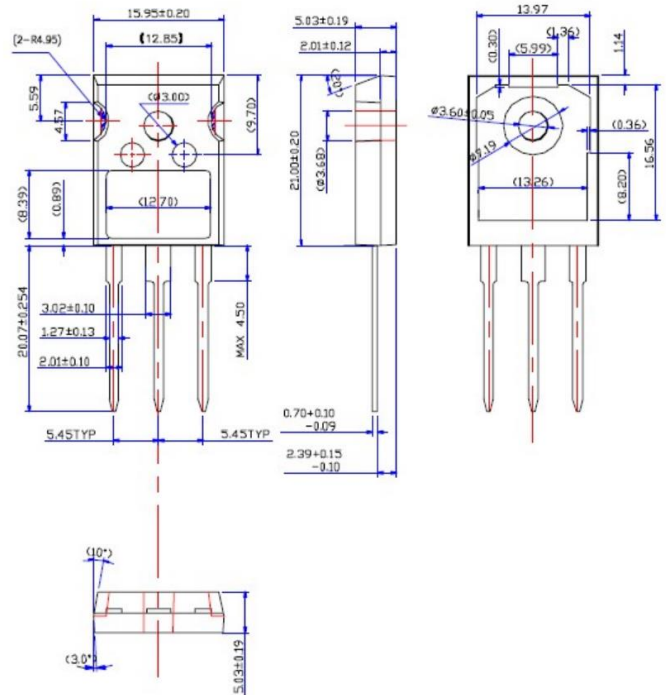
- RDS(on) (Max 1.4 Ω)@VGS=10V
- Gate Charge (Typical 45nC)
- Improved dv/dt Capability, High Ruggedness
- 100% Avalanche Tested
- Maximum Junction Temperature Range (150°C)
- RoHS compliant package

Package type : TO-247

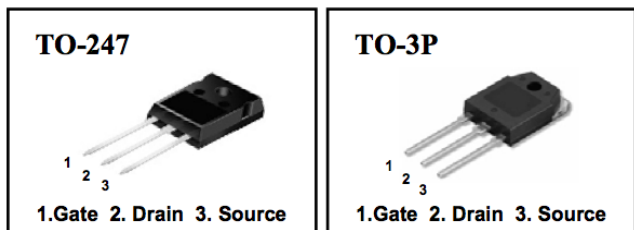
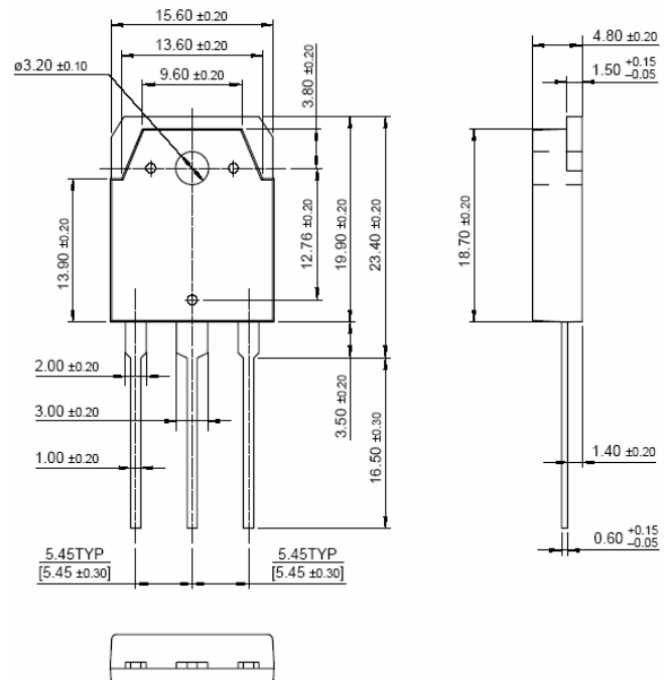
Packing & Order Information

50/Tube ; 1,000/Box

TO-247

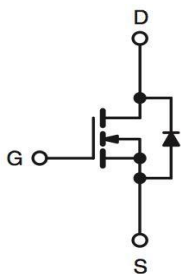


TO-3P



RoHS
COMPLIANT

Graphic symbol



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MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings (Tc=25°C unless otherwise noted)

| Symbol | Parameter | Value | Unit |
|----------------------------------|---|-------------|------|
| V _{DSS} | Drain-Source Voltage | 900 | V |
| V _{GS} | Gate-Source Voltage | ±30 | V |
| I _D | Drain Current -Continuous (TC=25°C) | 9 | A |
| | Drain Current -Continuous (TC=100°C) | 5.7 | A |
| I _{DM} | Drain Current Pulsed | 36 | A |
| E _{AS} | Single Pulsed Avalanche Energy | 900 | mJ |
| E _{AR} | Repetitive Avalanche Energy | 28 | mJ |
| dV/dt | Peak Diode Recovery dV/dt | 4 | V/ns |
| P _D | Power Dissipation (TC = 25 °C) | 280 | W |
| | - Derate above 25°C | 2.22 | W/°C |
| T _J ,T _{STG} | Operating and Storage Temperature Range | -55 to +150 | °C |
| T _L | Maximum lead temperature for soldering purposes, 1/8" from case for 5 seconds | 300 | °C |

- Drain current limited by maximum junction temperature

Thermal Resistance Characteristics

| Symbol | Parameter | Max. | Units |
|------------------|---------------------|------|-------|
| R _{θJC} | Junction-to-Case | 0.45 | °C/W |
| R _{θJA} | Junction-to-Ambient | 40 | |

On Characteristics

| Symbol | Test Conditions | Min | Typ. | Max. | Units |
|----------------------|--|-----|------|------|-------|
| V _{GS} | V _{DS} = V _{GS} , I _D = 250μA | 3.0 | -- | 5.0 | V |
| *R _{DS(ON)} | V _{GS} = 10 V , I _D = 4.5 A | -- | 1.05 | 1.4 | Ω |

Off Characteristics

| Symbol | Test Conditions | Min | Typ. | Max. | Units |
|--------------------------------------|---|-----|------|-----------|-------|
| BV _{DSS} | V _{GS} = 0 V , I _D = 250μA | 900 | -- | -- | V |
| ΔBV _{DSS} / ΔT _J | I _D = 250μA, Referenced to 25°C | -- | 0.99 | -- | V/°C |
| I _{DSS} | V _{DS} = 900 V , V _{GS} = 0 V V _{DS} = 720 V , V _C = 125°C | -- | -- | 10 100 | μA |
| I _{GSSF} | V _{GS} = 30 V , V _{DS} = 0 V | -- | -- | 100 | nA |
| I _{GSSR} | V _{GS} = -30 V , V _{DS} = 0 V | -- | -- | -100 | nA |

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Switching Characteristics

| Symbol | Test Conditions | Min | Typ. | Max. | Units |
|--------------|--|-----|------|------|-------|
| $t_{d(on)}$ | $V_{DS} = 450\text{ V}, I_D = 9\text{ A},$ $R_G = 25\ \Omega$ | -- | 50 | -- | ns |
| t_r | | -- | 120 | -- | ns |
| $t_{d(off)}$ | | -- | 100 | -- | ns |
| t_f | | -- | 80 | -- | ns |
| Q_g | $V_{DS} = 720\text{ V}, I_D = 9\text{ A},$ $V_{GS} = 10\text{ V}$ | -- | 45 | -- | nC |
| Q_{gs} | | -- | 14 | -- | nC |
| Q_{gd} | | -- | 18 | -- | nC |

Dynamic Characteristics

| Symbol | Test Conditions | Min | Typ. | Max. | Units |
|-----------|--|-----|------|------|-------|
| C_{iss} | $V_{DS} = 25\text{ V}, V_{GS} = 0\text{ V},$ $F = 1.0\text{ MHz}$ | -- | 2200 | -- | pF |
| C_{oss} | | -- | 180 | -- | pF |
| C_{rss} | | -- | 15 | -- | pF |

Source-Drain Diode Maximum Ratings and Characteristics

| Symbol | Parameter | Test Conditions | Min | Typ. | Max. | Units |
|----------|---|-----------------|-----|------|------|---------------|
| I_S | | | -- | -- | 9 | A |
| I_{SM} | | | -- | -- | 36 | |
| V_{SD} | $I_S = 9\text{ A}, V_{GS} = 0\text{ V}$ | | -- | -- | 1.5 | V |
| t_{rr} | $I_S = 9\text{ A}, V_{GS} = 0\text{ V}$ | | -- | 550 | -- | ns |
| Q_{rr} | $diF/dt = 100\text{ A}/\mu\text{s}$ | | -- | 6.5 | -- | μC |

Notes ;

1. Repetitive Rating: Pulse width limited by maximum junction temperature
2. $L = 21\text{ mH}, I_{AS} = 9\text{ A}, V_{DD} = 50\text{ V}, R_G = 25\ \Omega,$ Starting $T_J = 25^\circ\text{C}$
3. $I_{SD} \leq 9\text{ A}, di/dt \leq 200\text{ A}/\mu\text{s}, V_{DD} \leq BV_{DSS},$ Starting $T_J = 25^\circ\text{C}$
4. Pulse Test: Pulse Width $\leq 300\ \mu\text{s},$ Duty Cycle $\leq 2\%$
5. Essentially Independent of Operating Temperature

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